

Product Bulletin

Document # : PB22838X

Issue Date: 7 September 2019

Title of Change:		NCL2801 Datasheet Correction for Vcc, hyst (C and D Versions)				
Effective date:		7 September 2019				
Contact information:		Contact your local ON Semiconductor Sales Office or <marquita.jones@onsemi.com></marquita.jones@onsemi.com>				
Type of notification:		This Product Bulletin is for notification purposes only. ON Semiconductor will proceed with implementation of this change upon publication of this Product Bulletin.				
Change Category:		☐ Wafer Fab	Assembly Change	Test Change	✓ Other	Datasheet Change
	nge Sub-Category(s): Manufacturing Site Addition Manufacturing Site Transfer Manufacturing Process Chang	Product specific change		✓ Datasheet/Product Doc change☐ Shipping/Packaging/Marking☐ Other:		
Sites Affected:		ON Semiconductor Sites: None		External Foundry/Subcon Sites: None		
The product datasheet has been updated to reflect the correct specification for the Vcc, hyst (C and D Versions). This change is due to a datasheet typographical error. There has been no change in product manufacturing, die design, or bill of material.						
	Vcc hyst (C& D Versions)		Min	Тур		Max
	Before the change		3.3 V	3.6 V		3.9 V
	After the change		1.25 V	2.5 V		3.75 V
List of Affected Parts: Note: Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the PCN Customized Portal. NCL2801CDADR2G NCL2801CDBDR2G						

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